# Structure-property trends in $\boldsymbol{\pi}$-stacked dithiazolo-dithiazolyl conductors 

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The resonance stabilized dithiazolo-dithiazolyl radical 1b adopts a slipped $\pi$-stack structure exhibiting weak 1-D ferromagnetic coupling; variable temperature conductivity measurements indicate $\sigma_{\mathrm{RT}}=2 \times 10^{-6} \mathrm{~S} \mathrm{~cm}^{-1}$.

In an ideal neutral radical conductor a stack of $\pi$-radicals should function like an array of atoms in an elemental metal; the bulk material would possess a half-filled energy band, as in elemental sodium, and possess a metallic ground state. ${ }^{1}$ In practice, however, radicals tend to dimerize (a Peierls instability) ${ }^{2}$ and, more importantly, if association can be suppressed, the high on-site Coulomb repulsion $U(\approx \mathrm{IP}-\mathrm{EA})$ associated with most stable radicals leads to a Mott insulating state. ${ }^{3}$ The design of radicals with good ion energetics, i.e., low disproportionation enthalpies ( $\Delta H_{\text {disp }}=\mathrm{IP}-\mathrm{EA}$ ) is therefore crucial to the development of materials with enhanced conductivities. ${ }^{4}$ In this regard the resonance stabilized 1,2,3-dithia-zolo-1,2,3-dithiazolyl framework 1, with calculated $\Delta H_{\text {disp }}=$ 4.7 eV , represents an appealing building block. ${ }^{5}$ In the solid state, however, the recently reported compound $\mathbf{1 a}(\mathrm{R}=\mathrm{Cl})$ is a Mott insulator, as a result of slippage of the radical $\pi$-stacks and consequent loss of bandwidth $W .{ }^{5}$ In an effort to modify the crystal structure, and improve tranpsort properties, we have pursued the prototypal radical $\mathbf{1 b}(\mathrm{R}=\mathrm{H})$, in the belief that stack slippage might be reduced, and $W$ increased.



The reported preparative route to $\mathbf{1 a}$ involves N -methylation of the zwitterionic heterocycle $2(\mathrm{R}=\mathrm{Cl})^{6}$ with MeOTf followed by reduction of the resulting cation $[\mathbf{1}]^{+}$with $\mathrm{Cp}^{*}{ }_{2} \mathrm{Fe} .{ }^{5}$ We have now developed a much simpler route which provides easy access to both 1a and 1b. $\dagger$ Both syntheses involve, as a first step, N -methylation of 2,6-diaminopyridine with MeOTf to give 3. ${ }^{7}$ This reaction affords a mixture of protonated and methylated salts, ${ }^{8}$ from which the former can be removed by washing the crude product with $\mathrm{NEt}_{3}$ in $\mathrm{C}_{2} \mathrm{H}_{4} \mathrm{Cl}_{2}$. Subsequent treatment of $3(3.02 \mathrm{~g}, 11.0 \mathrm{mmol})$ with excess $\mathrm{S}_{2} \mathrm{Cl}_{2}(17.8 \mathrm{~g})$ at reflux in MeCN for 16 h affords a deep blue solution which, upon cooling, yields lustrous red plates of $[\mathbf{1 a}][\mathrm{OTf}](4.38 \mathrm{~g}$, $10.2 \mathrm{mmol}, 93 \%)$. If $\mathbf{3}(5.1 \mathrm{~g}, 18.9 \mathrm{mmol})$ and $\mathrm{S}_{2} \mathrm{Cl}_{2}(13.5 \mathrm{~g})$ are brought together in $\mathrm{CH}_{3} \mathrm{CN}$ at room temperature in the presence of $\mathrm{NEt}_{3}(11.6 \mathrm{~g}, 0.114 \mathrm{mmol})$ as an auxiliary base, and the mixture left to react for 5 days, a blue-black insoluble precipitate of $[\mathbf{1 b}][\mathrm{Cl}]$ is formed. Purification ${ }^{5}$ and metathesis of the latter with $\mathrm{AgSbF}_{6}$ in $\mathrm{CH}_{3} \mathrm{CN}$ generates a deep blue solution which, upon solvent removal and recrystallization from HOAc, affords deep red crystals of $[\mathbf{1 b}]\left[\mathrm{SbF}_{6}\right]$. Subsequent reduction of $[\mathbf{1 b}]\left[\mathrm{SbF}_{6}\right](0.943 \mathrm{~g}, 1.94 \mathrm{mmol})$ with $\mathrm{Cp}_{2}{ }_{2} \mathrm{Fe}$ $(0.634 \mathrm{~g}, 1.94 \mathrm{mmol})$ in degassed $\mathrm{CH}_{3} \mathrm{CN}$ affords $\mathbf{1 b},(0.425 \mathrm{~g}$,
$1.72 \mathrm{mmol}, 89 \%$ ), which may be recrystallized from degassed toluene as black needles.


The EPR spectrum of $\mathbf{1 b}$ in $\mathrm{CH}_{2} \mathrm{Cl}_{2}$ (Fig. 1) is consistent with the expected spin distribution, and can be simulated in terms of strong coupling from the two wing nitrogens, with weaker coupling to the central N , the unique proton and the N -methyl protons. Cyclic voltammetry on solutions of $[\mathbf{1 b}]\left[\mathrm{SbF}_{6}\right]$ in MeCN (Pt electrodes, $\mathrm{Bu}^{n}{ }_{4} \mathrm{NPF}_{6}$ supporting electrolyte) reveals a reversible reduction wave $\left(\mathbf{1 b}^{+/ 0}\right)$ with $E_{1 / 2}=-0.130 \mathrm{~V}$ ( vs . $\mathrm{SCE})$ and an irreversible reduction $\left(\mathbf{1 b}^{0 /-1}\right)$ with $E_{\mathrm{pc}}=-0.952$ V ( vs. SCE). As expected from the replacement of Cl by H , both these processes occur at slightly more cathodic potentials than those in $\mathbf{1 a} .{ }^{5}$ The peak-to-peak separation $E_{\mathrm{pc}}\left(\mathbf{1}^{+/ 0}\right)-E_{\mathrm{pc}}\left(\mathbf{1}^{0 /-1}\right)$ $=0.789 \mathbf{V}$ in $\mathbf{1 b}$ is smaller than $\mathbf{1 a}(0.830 \mathrm{~V})$. These data all militate in terms of a low on-site Coulomb repulsion U. ${ }^{9}$


Fig. 1 EPR spectrum ( $293 \mathrm{~K}, \mathrm{CH}_{2} \mathrm{Cl}_{2}, \mathrm{SW}=3 \mathrm{mT}, g=2.0082$ ) of radical 1b. Hyperfine coupling constants are $a_{\mathrm{N}}=0.317(2 \mathrm{~N})$ and $0.0620(1 \mathrm{~N}), a_{\mathrm{H}}$ $=0.230(1 \mathrm{H})$ and $0.034(3 \mathrm{H}) \mathrm{mT}$.

The crystal structure of radical $\mathbf{1 b} \ddagger$ belongs to the orthorhombic space group $P 2_{1} 2_{1} 2_{1}$, as does that of $\mathbf{1 a} .{ }^{5}$ The cell packing (Fig. 2), with radical $\pi$-stacks hinged around $2_{1}$ axes, is similar to that of $\mathbf{1 a}$. At 293 K the unit cell dimensions $b$ (15.194(5) $\AA$ in 1a, $11.962(3) \AA$ in 1b) and $c(15.069(4) \AA$ in 1a, 18.262(5) A in 1b) are, however, substantially different. The


Fig. 2 Unit cell of $\mathbf{1 b}$.
cell repeat distances $a$ also differ (4.2464(12) $\AA$ in $\mathbf{1 a}$, $3.9626(10) \AA$ in 1b). The latter parameters herald a change in the degree of slippage in the $\pi$-stacks. As illustrated in Fig. 3, the slippage angle $\tau$ (the angle between the mean molecular plane and the stacking axis) is larger for $\mathbf{1 b}$, i.e., the radicals are more nearly superimposed, as expected from the replacement of Cl by H . However, the plane-to-plane separation $\delta$ is also larger, suggesting that $\mathrm{Me} \cdots \mathrm{Me}$ repulsions are forcing the molecules apart as they slide on top of one another.§


Fig. 3 Slipped $\pi$-stacks in 1a (left) and 1b (right) illustrating the plate slippage angles $\tau\left(=54.81(13)^{\circ}\right.$ in $\mathbf{1 a}$ and $62.04(7)^{\circ}$ in $\left.\mathbf{1 b}\right)$ and mean plane separations $\delta(=3.470(5) \AA$ in $\mathbf{1 a}$ and 3.500(6) $\AA$ in 1b).

Magnetic susceptibility ( $\chi$ ) measurements on microcrystalline samples of $\mathbf{1 b}$ have been performed over the temperature range $320-5 \mathrm{~K}$. Like 1a, the temperature dependence of $\chi$ for $\mathbf{1 b}$ shows a Curie dependence down to near 100 K , with $C=0.345$, $\chi_{0}=120.4 \times 10^{-6} \mathrm{emu} \mathrm{mol}{ }^{-1}$. Consistently, the number of Curie spins (Fig. 4) remains constant near 0.92 down to 125 K , and then starts to rise. There is slight discontinuity at 85 K , which may signal a subtle phase change similar to that observed for 1a, after which the free spin count increases more sharply, reaching a value of 7.2 at 5 K . This enhancement is


Fig. 4 Number of Curie spins vs $T$ for $\mathbf{1 b}$.


Fig. 5 Single crystal conductivity of $\mathbf{1 b}$ as a function of $1 / T$.
characteristic of weak ferromagnetic coupling along the $\pi$ stacks. ${ }^{5,10}$

Single crystal conductivity ( $\sigma$ ) measurements along the needle axis of $\mathbf{1 b}$ over the temperature range $320-150 \mathrm{~K}$ indicate (Fig. 5) that the conductivity is activated, with a value of $\sigma=2 \times 10^{-6} \mathrm{~S} \mathrm{~cm}^{-1}$ at 300 K , i.e., very close to that found for 1a. ${ }^{5}$ The derived activation energy $\Delta$ (one-half of the band gap for an intrinsic semiconductor) is $0.41 \mathrm{eV}(0.42 \mathrm{eV}$ for 1a).

We attribute the similarity in the magnetic and conductivity behaviour of $\mathbf{1 a}$ and $\mathbf{1 b}$ to the combined effects of decreases in both $\tau$ and $\delta$. Because the changes offset one another, there is very little difference in (EHT calculated) intrastack overlap, and hence bandwidth $W$, between the two compounds. ${ }^{5}$

## Notes and references

$\dagger$ Satisfactory chemical analyses were obtained for $\mathbf{1 b}$ and $[\mathbf{1 b}]\left[\mathrm{SbF}_{6}\right]$. The IUPAC name for $\mathbf{1 b}$ is 4-methyl-4 $H$-bis[1,2,3]dithiazolo[4,5-b:5', $4^{\prime}$-e]pyr-idin-2-yl.
$\ddagger$ Crystal data for 1b: data were collected at 293 K on a Rigaku Mercury CCD diffractometer with graphite monochromated Mo $\mathrm{K} \alpha$ radiation ( $\lambda=$ $0.7107 \AA$ ) using $\omega$ scans. The structure was solved and refined by full matrix least-squares analysis which minimized $\Sigma w(\Delta F)^{2} . \mathrm{C}_{6} \mathrm{H}_{4} \mathrm{~N}_{3} \mathrm{~S}_{4}, M=246.36$, orthorhombic, space group $P 2_{1} 2_{1} 2_{1}$, with $a=3.9626(10), b=11.962(3)$, $c=18.262(5) \AA, V=865.6(4) \AA^{3}, Z=4, D_{\mathrm{c}}=1.890 \mathrm{~g} \mathrm{~cm}^{-3}, \mu=1.044$ $\mathrm{mm}^{-1} .134$ parameters were refined using 977 (all) unique reflections to give $R=0.0338$ and $R_{w}=0.0597$. CCDC 191497. See http://www.rsc.org/ suppdata/cc/b2/b207735n/ for crystallographic data in CIF or other electronic format.
§ Mean intramolecular distances (ranges in parentheses) for 1b: S-S, 2.097(10); S-N, 1.660(1); N-C, 1.311(6); S-C, 1.727(2) Å.

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